TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

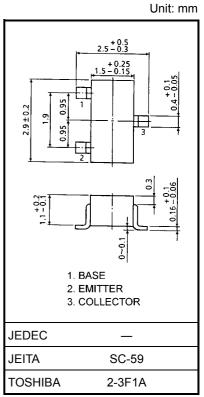
2SC3011

UHF~C Band Low Noise Amplifier Applications

- High gain: $|S_{21e}|^2 = 12 dB$ (typ.)
- Low noise figure: NF = 2.3dB (typ.), f = 1 GHz
- High f_T : $f_T = 6.5 \text{ GHz}$

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	20	V
Collector-emitter voltage	V _{CEO}	7	V
Emitter-base voltage	V _{EBO}	3	V
Collector current	Ι _C	30	mA
Emitter current	Ι _Ε	10	mA
Collector power dissipation	P _C	150	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.012 g (typ.)

Microwave Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Transition frequency	f _T	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 10 \text{ mA}$	_	6.5	_	GHz
Insertion gain	S _{21e} ²	V_{CE} = 5 V, I _C = 10 mA, f = 1 GHz		12		dB
Noise figure	NF	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 5 \text{ mA}, \text{ f} = 1 \text{ GHz}$	_	2.3	_	dB

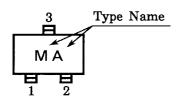
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB} = 10 V, I_E = 0$	_		1.0	μA
Emitter cut-off current	I _{EBO}	$V_{EB} = 1.0 \text{ V}, \text{ I}_{C} = 0$	_	—	1.0	μA
Collecter-emitter breakdown voltage	V (BR) CEO	$I_{C} = 0.5 \text{ mA}, I_{B} = 0$	7	—	_	V
DC current gain	h _{FE}	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	30	120	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 10 mA, I _B = 1 mA	_	0.1	_	V
Base-emitter saturation voltage	V _{BE (sat)}		_	0.87	_	V
Collecter output capacitance	C _{ob}	$V_{CB} = 5 V, I_E = 0, f = 1 MHz$ (Note)	_	0.7	0.9	pF
Reverse transfer capacitance	C _{re}		_	0.5	_	pF
Input capacitance	C _{ib}	$V_{EB}=0,\ I_C=0,\ f=1\ MHz$	_	0.8	_	pF

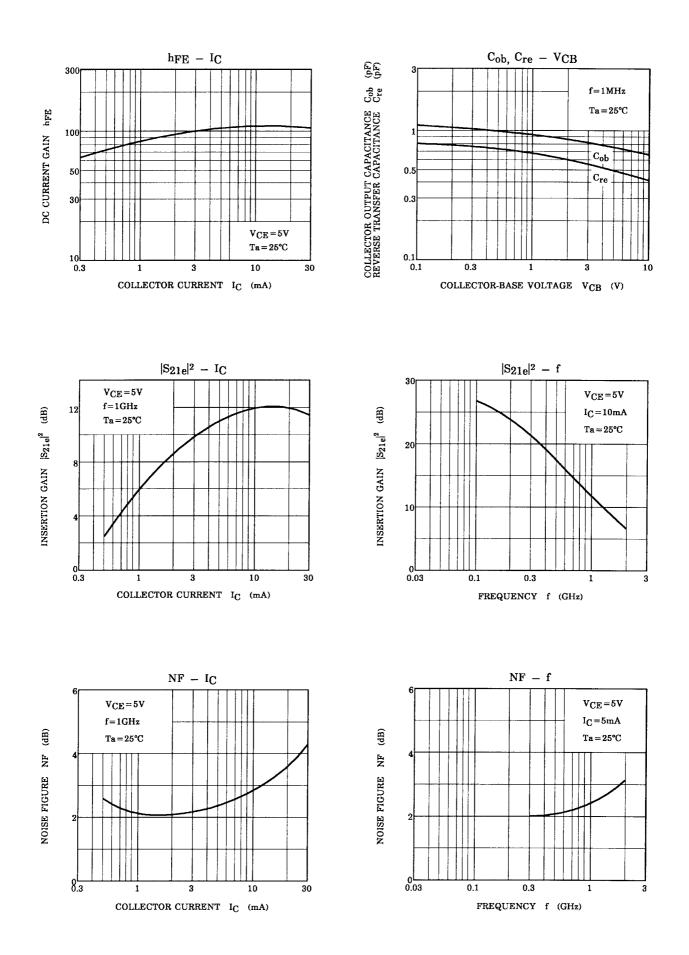
Note: C_{re} is measured by 3-terminal method with capacitance bridge.

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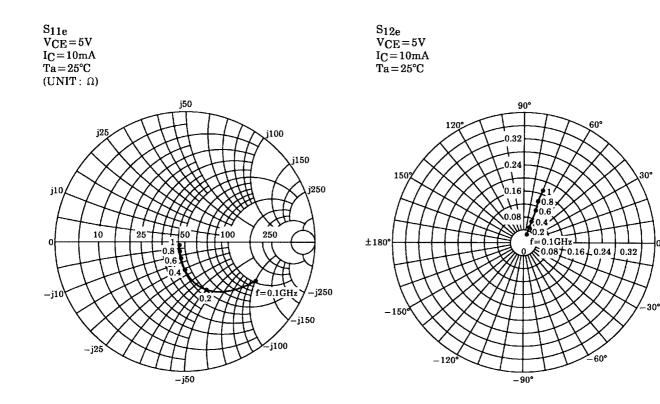
Marking



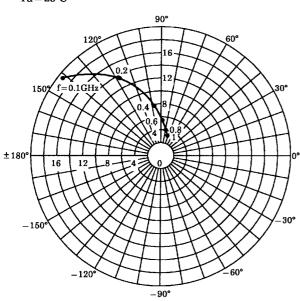
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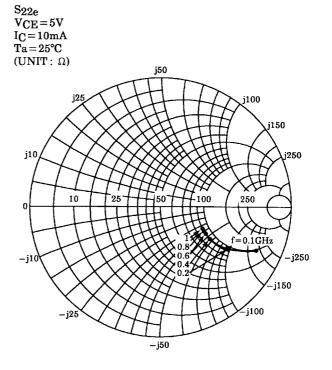


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